

36V Stepping Motor Driver

BD68610EFV

●General Description

BD68610EFV is a bipolar low-consumption driver that driven by PWM current. Rated power supply voltage of the device is 36 V, and rated output current is 1.0A. PALA-IN driving mode is adopted for input interface. In terms of current decay, the FAST DECAY/SLOW DECAY ratio may be set without any limitation, and all available modes may be controlled in the most appropriate way. In addition, the power supply may be driven by one single system, which simplifies the design.

●Features

- Rated output current (DC) 1.0A
- Low ON resistance DMOS output
- PALA-IN drive mode
- PWM constant current (other oscillation)
Built-in spike noise cancel function (external noise filter is unnecessary)
- Full-, half (two kinds)-, quarter-step functionality
- Current decay mode switch
(linearly variable FAST/SLOW DECAY ratio)
- Power save function
- Built-in logic input pull-down resistor
- Thermal shutdown circuit (TSD)
- Over-current protection circuit (OCP)
- Under voltage lock out circuit (UVLO)
- Over voltage lock out circuit (OVLO)
- Ghost Supply Prevention (protects against malfunction when power supply is disconnected)
- Microminiature, ultra-thin and high heat-radiation (exposed metal type) package

●Application

- PPC, multi-function printer, laser beam printer, and ink-jet printer
- Monitoring camera and WEB camera
- Sewing machine
- Photo printer, FAX, scanner and mini printer
- Toy and robot

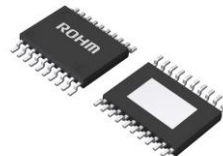
●Major Characteristics

- Range of power supply voltage 19~28 [V]
- Rated output current (peak value) 1.0 [A]
- Range of operating temperature -25~+85 [°C]
- Output ON resistance (total of upper and lower resistors) 1.5 [Ω] (Typ.)

●Package

HTSSOP-B20

W(Typ.) x D(Typ.)x H(Max.)
6.50mm x6.40mm x 1.00mm



●Basic application circuit

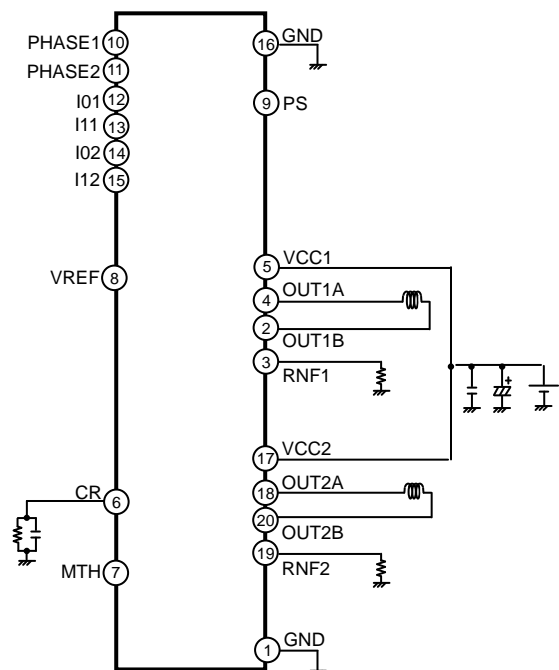


Figure 1. BD68610EFV application circuit diagram

Terminals Configuration Diagram

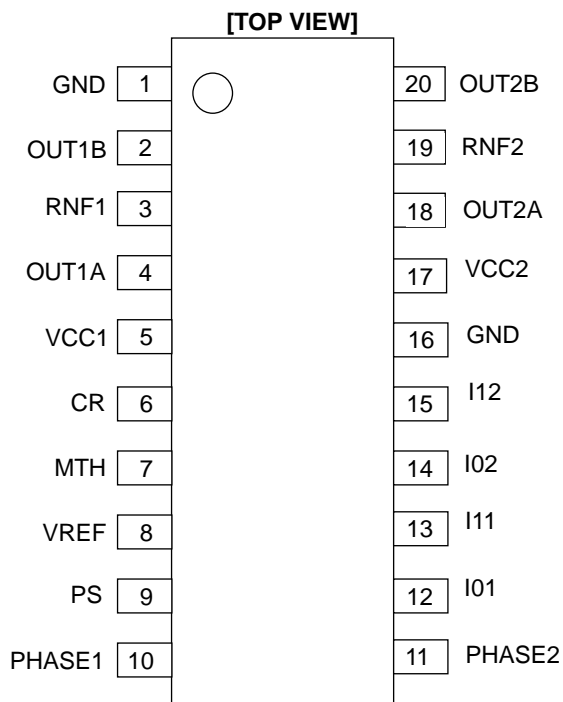


Figure 2. Terminals Configuration Diagram

Block Diagram

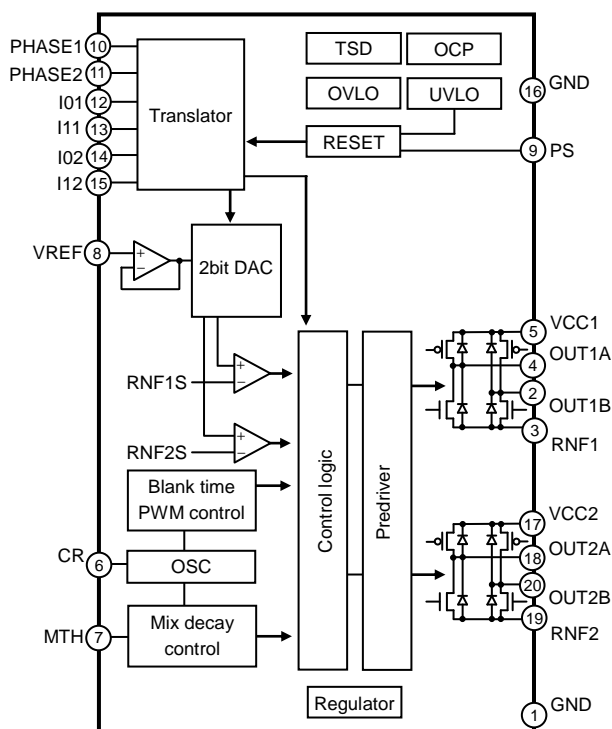


Figure 3. BD68610EFV Block Diagram

Descriptions on Terminals

| NO. | Designation | Function | NO. | Designation | Function |
|-----|-------------|--|-----|-------------|--|
| 1 | GND | Ground terminal | 11 | PHASE2 | Phase selection terminal |
| 2 | OUT1B | H bridge output terminal | 12 | I01 | VREF division ratio setting terminal |
| 3 | RNF1 | Connection terminal of resistor for output current detection | 13 | I11 | VREF division ratio setting terminal |
| 4 | OUT1A | H bridge output terminal | 14 | I02 | VREF division ratio setting terminal |
| 5 | VCC1 | Power supply terminal | 15 | I12 | VREF division ratio setting terminal |
| 6 | CR | Connection terminal of CR for | 16 | GND | Ground terminal |
| 7 | MTH | Current decay mode setting t | 17 | VCC2 | Power supply terminal |
| 8 | VREF | Output current value setting terminal | 18 | OUT2A | H bridge output terminal |
| 9 | PS | Power save terminal | 19 | RNF2 | Connection terminal of resistor for output current detection |
| 10 | PHASE1 | Phase selection terminal | 20 | OUT2B | H bridge output terminal |

●Absolute Maximum Rated Values (Ta=25°C)

| Item | Symbol | Rated Value | Unit |
|-------------------------------|--------------------|--------------------|---------|
| Supply voltage | V _{CC1,2} | -0.2~+36.0 | V |
| Power dissipation | Pd | 1.00 ^{*1} | W |
| | | 3.20 ^{*2} | W |
| Input voltage for control pin | V _{IN} | -0.2~+5.5 | V |
| RNF maximum voltage | V _{RNF} | 0.7 | V |
| Output current | I _{OUT} | 1.0 ^{*3} | A/Phase |
| Operating temperature range | T _{opr} | -25~+85 | °C |
| Storage temperature range | T _{stg} | -55~+150 | °C |

*1 70mm×70mm×1.6mm glass epoxy board. Derating in done at 8.0mW/°C for operating above Ta=25°C.

*2 4-layer recommended board. Derating in done at 25.6mW/°C for operating above Ta=25°C.

*3 Do not, however exceed Pd, ASO and Tjmax=150°C.

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

●Recommended operating range (Ta= -25~+85°C)

| Item | Symbol | Rated Value | Unit |
|-----------------------------|--------------------|-------------------|----------|
| Supply voltage | V _{CC1,2} | 19~28 | V |
| Maximum Output current (DC) | I _{OUT} | 0.6 ^{*4} | A/ Phase |

*4 Not exceeding Pd, ASO or Tj=150°C

●Electrical Characteristics (Unless otherwise specified Ta=25°C, V_{CC1,2}=24V)

| Item | Symbol | Specification | | | Unit | Condition |
|--|--------------------|---------------|----------|---------|------|--|
| | | Minimum | Standard | Maximum | | |
| [Whole] | | | | | | |
| Circuit current at standby | I _{CCST} | - | 0.4 | 1.5 | mA | PS=L |
| Circuit current | I _{CC} | - | 1.3 | 4.0 | mA | PS=H, VREF=3V |
| [Control input](PHASE1, PHASE2) | | | | | | |
| H-level input voltage | V _{IN1H} | 2.8 | - | - | V | |
| L-level input voltage | V _{IN1L} | - | - | 0.6 | V | |
| H-level input current | I _{IN1H} | 35 | 50 | 100 | μA | V _{IN1} =5V |
| L-level input current | I _{IN1L} | -10 | 0 | - | μA | V _{IN1} =0V |
| [Control input] (PS, I01, I11, I02, I12) | | | | | | |
| H-level input voltage | V _{IN2H} | 2.0 | - | - | V | |
| L-level input voltage | V _{IN2L} | - | - | 0.8 | V | |
| H-level input current | I _{IN2H} | 35 | 50 | 100 | μA | V _{IN2} =5V |
| L-level input current | I _{IN2L} | -10 | 0 | - | μA | V _{IN2} =0V |
| [Output (OUT1A, OUT1B, OUT2A, OUT2B)] | | | | | | |
| Output ON resistance | R _{ON} | - | 1.5 | 1.95 | Ω | I _{OUT} =± 1.5A (Sum of upper and lower) |
| Output leak current | I _{LEAK} | - | - | 10 | μA | |
| [Current control] | | | | | | |
| RNFx input current | I _{RNF} | -80 | -40 | - | μA | RNFx=0V |
| VREF input current | I _{VREF} | -2.0 | -0.1 | - | μA | VREF=0V |
| VREF input voltage range | V _{VREF} | 0 | - | 3.0 | V | |
| MTH input current | I _{MTH} | -2.0 | -0.1 | - | μA | MTH=0V |
| MTH input voltage range | V _{MTH} | 0 | - | 3.5 | V | |
| Minimum ON time (Blank time) | t _{ONMIN} | 0.3 | 0.9 | 1.5 | μs | C=1000pF, R=39kΩ |
| Comparator threshold | V _{CTH} | 0.57 | 0.60 | 0.63 | V | VREF=3V |

●Function explanation

OPS/Power save terminal

PS can make circuit standby state and make motor output OPEN. When PS=L⇒H, please be careful because there is a delay of 40μs(max.) before it is returned from standby state to normal state and the motor output becomes ACTIVE.

| PS | Status |
|----|---------------|
| L | Standby state |
| H | ACTIVE |

OPHASE1,PHASE2/Phase selection terminal

These terminals determine output state.

| PHASE1 | PHASE2 | OUT1A | OUT1B | OUT2A | OUT2B |
|--------|--------|-------|-------|-------|-------|
| L | L | L | H | L | H |
| H | L | H | L | L | H |
| L | H | L | H | H | L |
| H | H | H | L | H | L |

OI01,OI02,I11,I12/VREF division ratio setting terminal

These terminals determine internal 2bit-DAC output voltage for current limit.

| IOx | I1x | Output current level(%) |
|-----|-----|-------------------------|
| L | L | 100 |
| H | L | 67 |
| L | H | 33 |
| H | H | 0 |

(IOX, I1X)=(H, H): motor outputs are open.

OVCC1,VCC2/Power supply terminal

Motor's drive current is flowing in it, so please wire in such a way that the wire is thick & short and has low impedance.

Voltage VCC may have great fluctuation, so please arrange the bypass capacitor of about 100 μ ~ 470 μ F as close to the terminal as possible and adjust in such a way that the voltage VCC is stable. Please increase the capacity if needed especially when a large current is used or those motors that have great back electromotive force are used.

In addition, for the purpose of reducing of power supply's impedance in wide frequency bandwidth, parallel connection of multi-layered ceramic capacitor of 0.01 μ ~ 0.1 μ F etc is recommended. Extreme care must be used to make sure that the voltage VCC does not exceed the rating even for a moment.

VCC1 & VCC2 are shorted inside IC, so please be sure to short externally VCC1 & VCC2 when using. If used without shorting, malfunction or destruction may occur because of concentration of current routes etc., so please make sure that they are shorted when in use. Still more, in the power supply terminal, there is built-in clamp component for preventing of electrostatic destruction. If steep pulse or voltage of surge more than maximum absolute rating is applied, this clamp component operates, as a result there is the danger of destruction, so please be sure that the maximum absolute rating must not be exceeded. It is effective to mount a Zener diode of about the maximum absolute rating. Moreover, the diode for preventing of electrostatic destruction is inserted between VCC terminal and GND terminal, as a result there is the danger of IC destruction if reverse voltage is applied between VCC terminal and GND terminal, so please be careful.

OGND/Ground terminal

In order to reduce the noise caused by switching current and to stabilize the internal reference voltage of IC, please wire in such a way that the wiring impedance from this terminal is made as low as possible to achieve the lowest electrical potential no matter what operating state it may be. Moreover, please design patterns not to have any common impedance with other GND patterns.

OOOUT1A,OUT1B,OUT2A,OUT2B/H Bridge output terminal

Motor's drive current is flowing in it, so please wire in such a way that the wire is thick & short and has low impedance. It is also effective to add a Schottky diode if output has positive or negative great fluctuation when large current is used etc, for example, if counter electromotive voltage etc. is great. Moreover, in the output terminal, there is built-in clamp component for preventing of electrostatic destruction. If steep pulse or voltage of surge more than maximum absolute rating is applied, this clamp component operates, as a result there is the danger of even destruction, so please be sure that the maximum absolute rating must not be exceeded.

ORNF1,RNF2/Connection terminal of resistor for detecting of output current

Please connect the resistor of 0.1 Ω ~ 0.3 Ω for current detection between this terminal and GND In view of the power consumption of the current-detecting resistor, please determine the resistor in such a way that $W=I_{OUT2} \cdot R[W]$ does not exceed the power dissipation of the resistor. In addition, please wire in such a way that it has a low impedance and does not have a impedance in common with other GND patterns because motor's drive current flows in the pattern through RNF terminal~current-detecting resistor~GND. Please do not exceed the rating because there is the possibility of circuits' malfunction etc. if RNF voltage has exceeded the maximum rating (0.7V). Moreover, please be careful because if RNF

terminal is shorted to GND, large current flows without normal PWM constant current control, then there is the danger that OCP or TSD will operate. If RNF terminal is open, then there is the possibility of such malfunction as output current does not flow either, so please do not let it open.

OVREF/Output current value setting terminal

This is the terminal to set the output current value. The output current value can be set by VREF voltage and current-detecting resistor (RNF resistor).

Output current $I_{OUT}[A] = \{VREF[V] / 5(\text{division ratio inside IC})\} / \{RNF[\Omega] + \beta\}$

β : RNF terminal resistor (reference value), min.25m Ω / typ.30m Ω / max.35m Ω

Please avoid using it with VREF terminal open because if VREF terminal is open, the input is unsettled, and the VREF voltage increases, and then there is the possibility of such malfunctions as the setting current increases and a large current flows etc. Please keep to the input voltage range because if the voltage of over 3V is applied on VREF terminal, then there is also the danger that a large current flows in the output and so OCP or TSD will operate. Besides, please take into consideration the outflow current (max.2 μ A) if inputted by resistance division when selecting the resistance value. The minimum current, which can be controlled by VREF voltage, is determined by motor coil's L & R values and minimum ON time because there is a minimum ON time in PWM drive.

OCR/Connection terminal of CR for setting chopping frequency

This is the terminal to set the chopping frequency of output. Please connect the external C(470p~1500pF) and R(10k~200k Ω) between this terminal and GND. Please refer to P8. Please interconnect from external components to GND in such a way that the interconnection does not have impedance in common with other GND patterns. In addition, please carry out the pattern design in such ways as keeps such steep pulses as square wave etc. away and that there is no noise plunging. Please mount the two components of C and R if being used by PWM constant current control because normal PWM constant current control becomes impossible if CR terminal is open or it is biased externally.

OMTH/Current decay mode-setting terminal

This is the terminal to set the current decay mode. Current decay mode can be optionally set according to input voltage.

| MTH terminal input voltage[V] | Current decay mode |
|-------------------------------|--------------------|
| 0~0.3 | SLOW DECAY |
| 0.4~1.0 | MIX DECAY |
| 1.5~3.5 | FAST DECAY |

Please connect to GND if using at SLOW DECAY mode.

Please avoid using with MTH terminal open because if MTH terminal is open, the input is unsettled, and then there is the danger that PWM operation becomes unstable. Besides, please take into consideration the outflow current (max.2 μ A) if inputted by resistance division when selecting the resistance value.

ONC terminal

This terminal is unconnected electrically with IC internal circuit.

○Thermal Shutdown (TSD)

This IC has a built-in thermal shutdown circuit for thermal protection. When the IC's chip temperature rises above 175°C(Typ.), the motor output becomes OPEN. Also, when the temperature returns to under 150°C (Typ.), it automatically returns to normal operation. However, even when TSD is in operation, if heat is continued to be added externally, heat overdrive can lead to destruction.

○Over Current Protection (OCP)

This IC has a built in over current protection circuit as a provision against destruction when the motor outputs are shorted each other or VCC-motor output or motor output-GND is shorted. This circuit latches the motor output to OPEN condition when the regulated threshold current flows for 4μs (Typ.). It returns with power reactivation or a reset of the PS terminal. The over current protection circuit's only aim is to prevent the destruction of the IC from irregular situations such as motor output shorts, and is not meant to be used as protection or security for the set. Therefore, sets should not be designed to take into account this circuit's functions. After OCP operating, if irregular situations continues and the return by power reactivation or a reset of the PS terminal is carried out repeatedly, then OCP operates repeatedly and the IC may generate heat or otherwise deteriorate. When the L value of the wiring is great due to the wiring being long, after the over current has flowed and the output terminal voltage jumps up and the absolute maximum values may be exceeded and as a result, there is a possibility of destruction. Also, when current which is over the output current rating and under the OCP detection current flows, the IC can heat up to over $T_{jmax}=150^{\circ}\text{C}$ and can deteriorate, so current which exceeds the output rating should not be applied.

○Under Voltage Lock Out (UVLO)

This IC has a built-in under voltage lock out function to prevent false operation such as IC output during power supply under voltage. When the applied voltage to the VCC terminal goes under 15V (Typ.), the motor output is set to OPEN. This switching voltage has a 1V (Typ.) hysteresis to prevent false operation by noise etc. Please be aware that this circuit does not operate during power save mode. Also, the electrical angle is reset when the UVLO circuit operates during CLK-IN drive mode.

○Over Voltage Lock Out (OVLO)

This IC has a built-in over voltage lock out function to protect the IC output and the motor during power supply over voltage. When the applied voltage to the VCC terminal goes over 32V (Typ.), the motor output is set to OPEN. This switching voltage has a 1V (Typ.) hysteresis and a 4μs (Typ.) mask time to prevent false operation by noise etc. Although this over voltage locked out circuit is built-in, there is a possibility of destruction if the absolute maximum value for power supply voltage is exceeded, therefore the absolute maximum value should not be exceeded. Please be aware that this circuit does not operate during power save mode.

○Ghost Supply Prevention (protects against malfunction when power supply is disconnected)

If a signal (logic input, MTH, VREF) is input when there is no power supplied to this IC, there is a function which prevents the false operation by voltage supplied via the electrostatic destruction prevention diode from these input terminals to the VCC to this IC or to another IC's power supply. Therefore, there is no malfunction of the circuit even when voltage is supplied to these input terminals while there is no power supply.

OPWM Constant current control

1) Current control operation

When the output transistor is turned on, the output current increases, raising the voltage over the current sense resistor. When the voltage on the RNF pin reaches the voltage value set by the internal 2-bit DAC and the VREF input voltage, the current limit comparator engages and enters current decay mode. The output is then held off for a period of time determined by the RC time constant connected to the CR pin. The process repeats itself constantly for PWM operation.

2) Noise-masking function

In order to avoid misdetection of output current due to RNF spikes that may occur when the output turns ON, the IC employs an automatic current detection-masking period (t_{ONMIN}), during which current detection is disabled immediately after the output transistor is turned on. This allows for constant-current drive without the need for an external filter. This noise-masking period defines the minimum ON-time for the motor output transistor.

3) CR Timer

The CR filter connected to the CR pin is repeatedly charged and discharged between the VCRH and VCRL levels. The output of the internal comparator is masked while charging from VCRL to VCRH in order to cancel noise. (As mentioned above, this period defines the minimum ON-time of the motor output transistor.) The CR terminal begins discharging once the voltage reaches VCRH. When the output current reaches the current limit during this period (i.e. RNF voltage reaches the decay trigger voltage), then the IC enters decay mode. The CR continues to discharge during this period until it reaches VCRL, at which point the IC output is switched back ON. The current output and CR pin begin charging simultaneously. The CR charge time (t_{ONMIN}) and discharge time ($t_{discharge}$) are set by external components, according to the following formulas. The total of t_{ONMIN} and $t_{discharge}$ yield the chopping period, t_{chop} .

$$t_{ONMIN}[s] \doteq C \cdot R' \cdot R / (R' + R) \cdot \ln[(VCR - 0.4)/(VCR - 1.0)]$$

$$VCR = V \cdot R / (R' + R)$$

V : internal regulator voltage 5V(Typ.)

R': CR terminal internal impedance 5kΩ(Typ.)

$$t_{discharge}[s] \doteq C \cdot R \cdot \ln[(1 + \alpha)/0.4]$$

α : See the right graph

$$t_{CHOP}[s] \doteq t_{ONMIN} + t_{discharge}$$

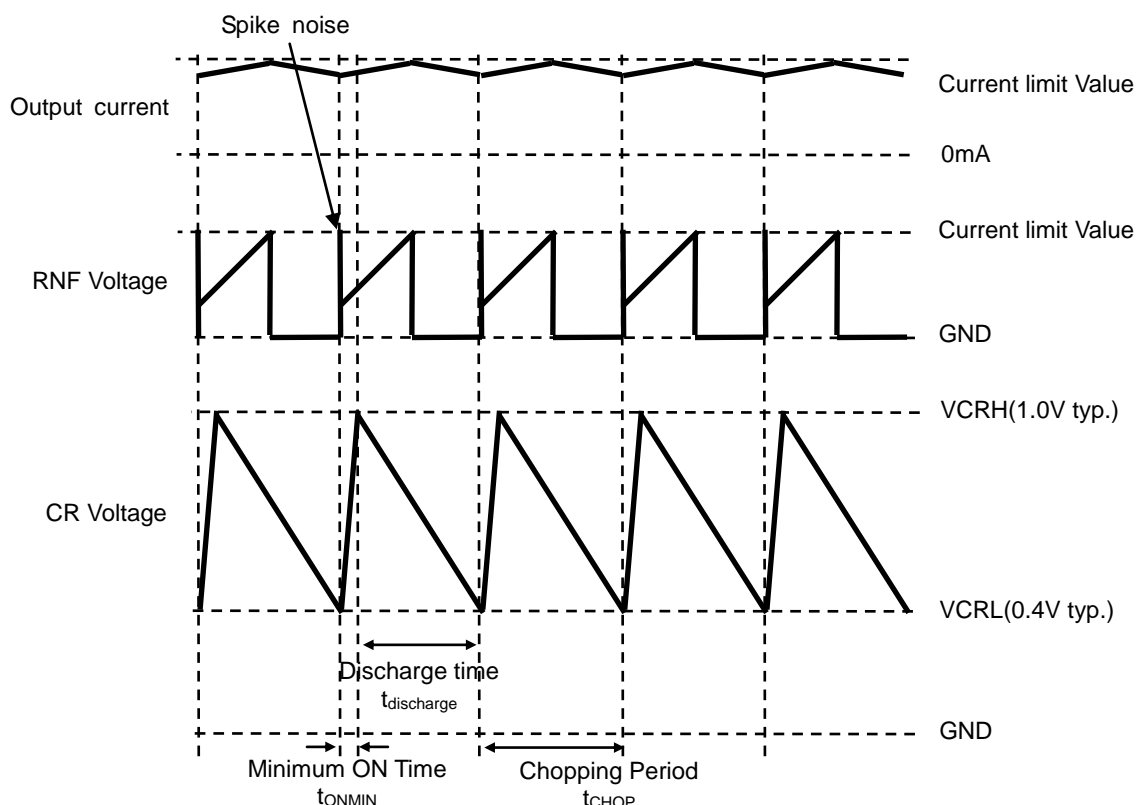
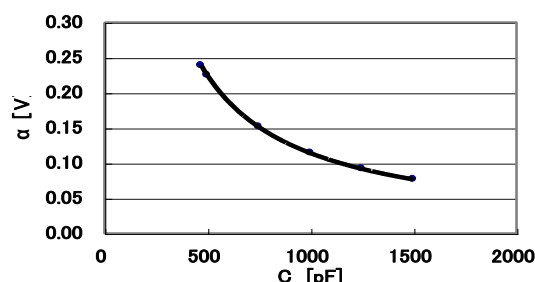


Figure 4. Timing chart of CR voltage, RNF voltage and output current

Attach a resistor of at least 10 kΩ to the CR terminal (10 kΩ~200 kΩ recommended) as lower values may keep the RC from reaching the VCRH voltage level. A capacitor in the range of 470 pF – 1500 pF is also recommended. As the capacitance value is increased, however, the noise-masking period (t_{onmin}) also increases, and there is a risk that the output current may exceed the current limit threshold due to the internal L and R components of the output motor coil. Also, ensure that the chopping period (t_{chop}) is not set longer than necessary, as doing so will increase the output ripple, thereby decreasing the average output current and yielding lower output rotation efficiency. The optimal value should reduce the motor drive noise while keeping distortion of the output current waveform to a minimum.

○ Current decay mode

The IC allows for a mixed decay mode in which the ratio of fast and slow decay can be optionally set.

The following diagrams show the operating state of each transistor and the regenerative current path during attenuation for each decay mode:

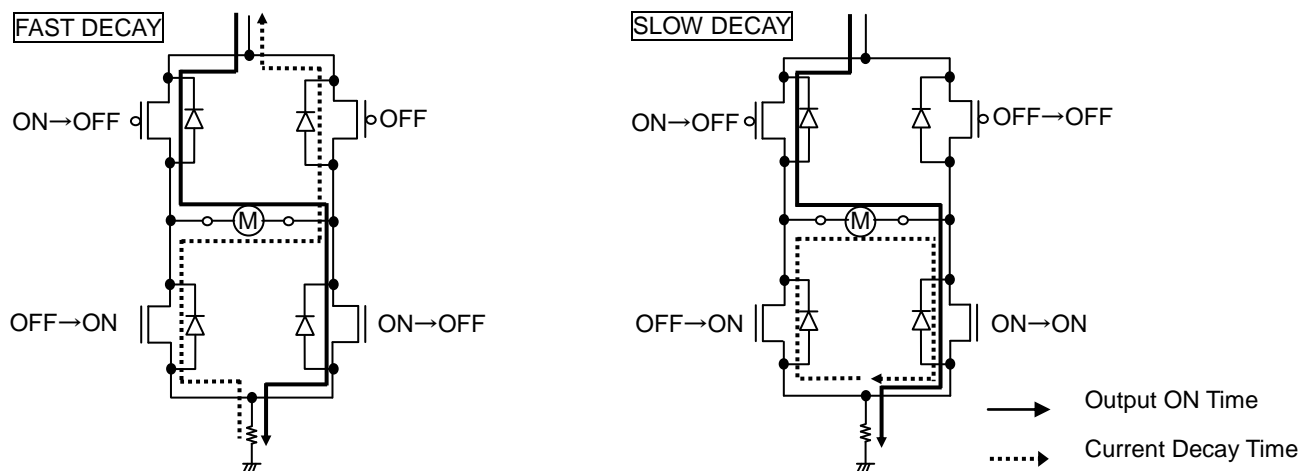


Figure 5. Route of Regenerated Current during Current Decay

The merits of each decay mode are as follows:

○ SLOW DECAY

During current attenuation, the voltage between motor coils is small and the regeneration current decreases slowly, decreasing the output current ripple. This is favorable for keeping motor torque high. However, due to fall-off of current control characteristics in the low-current region, or due to reverse EMF of the output motors exhibited when using high-pulse-rate half-step or quarter-step modes, the output current increases, distorting the output current waveform and increasing motor vibration. Thus, this decay mode is most suited to full-step modes, or low-pulse-rate half-step or quarter-step modes.

○ FAST DECAY

Fast decay decreases the regeneration current much more quickly than slow decay, greatly reducing distortion of the output current waveform. However, fast decay yields a much larger output current ripple, which decreases the overall average current running through the motor. This causes two problems: first, the motor torque decreases (increasing the current limit value can help eliminate this problem, but the rated output current must be taken into consideration); and second, the power loss within the motor increases and thereby radiates more heat. If neither of these problems is of concern, then fast decay can be used for high-pulse rate half- or quarter-step drive.

Additionally, this IC allows for a mixed decay mode that can help improve upon problems that arise from using fast or slow decay alone. In this mode, the IC switches automatically between slow and fast decay, improving the current control characteristics without increasing the output current ripple. Mixed decay mode operates by splitting the decay period into two sections, the first $X\%$ (t_1-t_2) of which operates the IC in slow decay mode, and the remainder (t_2-t_3) of which operates in fast decay mode. However, if the output current (i.e., the voltage on the RNF pin) does not reach the set current limit during the first $X\%$ (t_1-t_2) decay period, the IC operates in fast decay mode only.

| MTH voltage [V] | Current decay mode |
|-----------------|--------------------|
| 0~0.3 | SLOW DECAY |
| 0.4~1.0 | MIX DECAY |
| 1.5~3.5 | FAST DECAY |

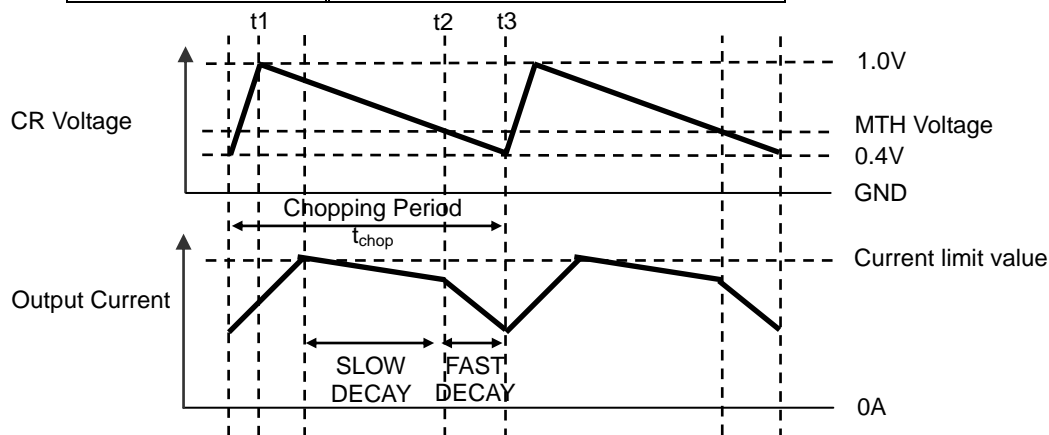


Figure 6. Relation between CR terminal voltage, MTH voltage, and output current during mixed decay

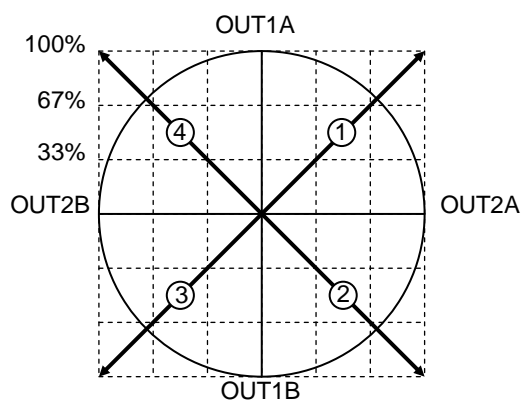
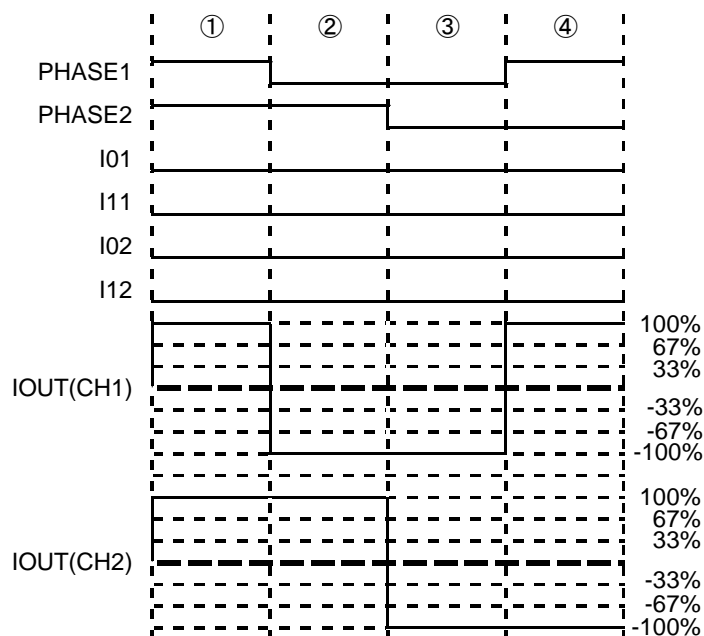
● PARALLEL-IN drive mode

It is possible to drive stepping motor with FULL STEP, HALF STEP, and QUARTER STEP by inputting the following motor control signals using PARALLEL-IN drive mode.

Examples of control sequence and torque vector

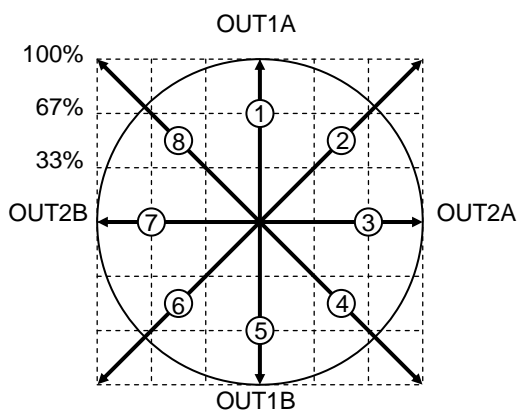
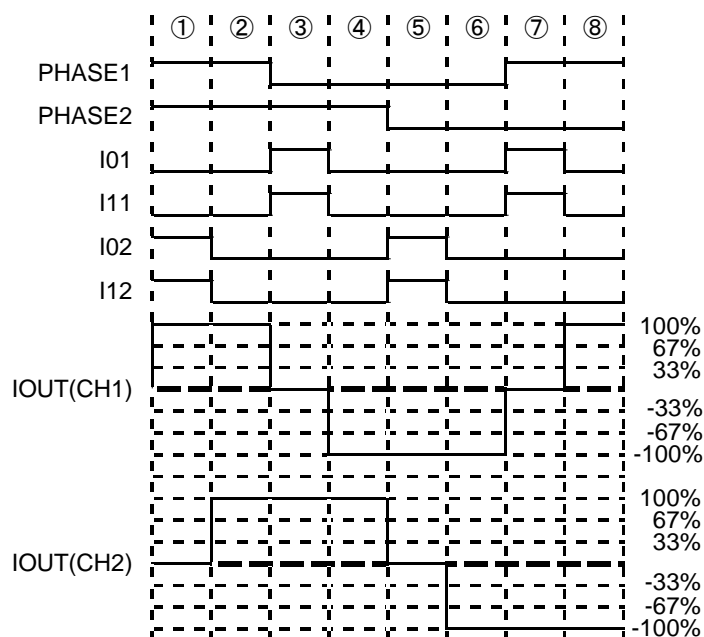
FULL STEP

Controlled by 2 logic signals of PHASE1 & PHASE2



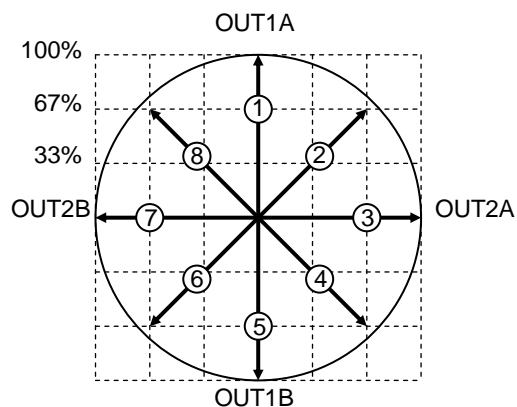
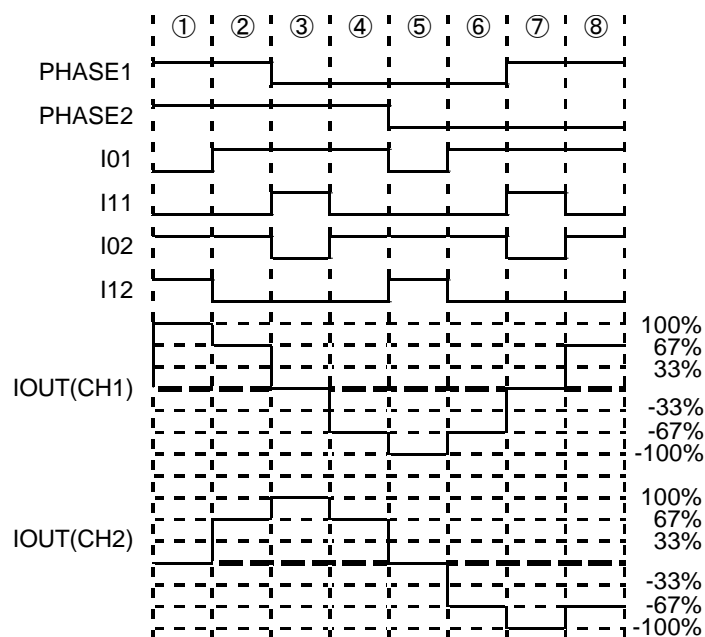
HALF STEP A

Controlled by 4 logic signals of PHASE1, PHASE2, I01(I11), and I02(I12)



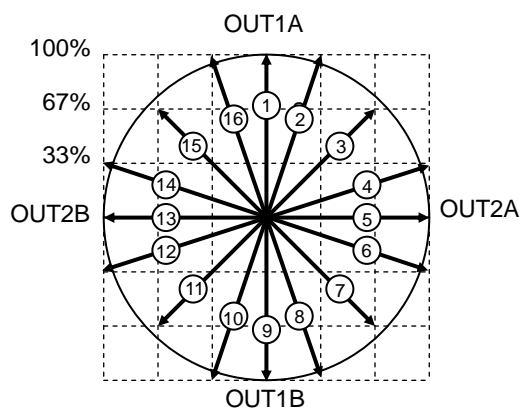
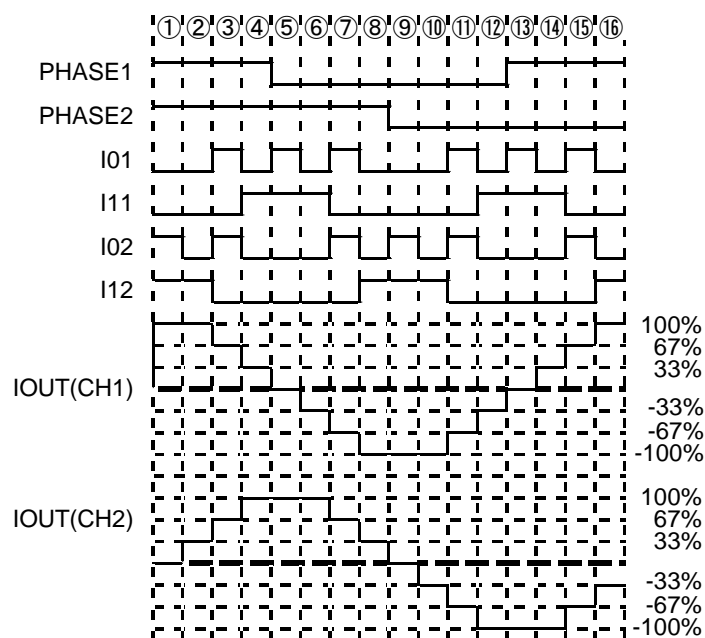
HALF STEP B

Controlled by 6 logic signals of PHASE1, PHASE2, I01, I11, I02, and I12



QUARTER STEP

Controlled by 6 logic signals of PHASE1, PHASE2, I01, I11, I02, and I12



●Power dissipation

Please confirm that the IC's chip temperature T_j is not over 150°C , while considering the IC's power consumption (W), package power (P_d) and ambient temperature (T_a). When $T_j=150^{\circ}\text{C}$ is exceeded the functions as a semiconductor do not operate and problems such as parasitism and leaks occur. Constant use under these circumstances leads to deterioration and eventually destruction of the IC. $T_{j\text{max}}=150^{\circ}\text{C}$ must be strictly obeyed under all circumstances.

○Thermal Calculation

The IC's consumed power can be estimated roughly with the power supply voltage (V_{CC}), circuit current (I_{CC}), output ON resistance (R_{ONH} , R_{ONL}) and motor output current value (I_{OUT}).

The calculation method during FULL STEP drive, SLOW DECAY mode is shown here:

$$\text{Consumed power of the } V_{CC} [W] = V_{CC} [V] \cdot I_{CC} [A] \quad \cdots \cdots \textcircled{1}$$

$$\begin{aligned} \text{Consumed power of the output DMOS } [W] = & (R_{ONH} [\Omega] + R_{ONL} [\Omega]) \cdot I_{OUT} [A]^2 \cdot 2[\text{ch}] \cdot \text{on_duty} \\ & \text{During output ON} \\ & + (2 \cdot R_{ONL} [\Omega]) \cdot I_{OUT} [A]^2 \cdot 2[\text{ch}] \cdot (1 - \text{on_duty}) \quad \cdots \cdots \textcircled{2} \\ & \text{During current decay} \end{aligned}$$

However, on duty: PWM on duty = $t_{on} / (t_{chop})$

t_{on} varies depending on the L and R values of the motor coil and the current set value. Please confirm by actual measurement, or make an approximate calculation.

t_{chop} is the chopping period, which depends on the external CR. See P.8 for details.

| IC number | Upper PchDMOS ON Resistance $R_{ONH} [\Omega]$ (Typ.) | Lower NchDMOS ON Resistance $R_{ONL} [\Omega]$ (Typ.) |
|------------|--|--|
| BD68610EFV | 0.87 | 0.63 |

$$\text{Consumed power of total IC } W_{\text{total}} [W] = \textcircled{1} + \textcircled{2}$$

$$\text{Junction temperature } T_j [^{\circ}\text{C}] = T_a [^{\circ}\text{C}] + \theta_{ja} [^{\circ}\text{C/W}] \cdot W_{\text{total}} [W]$$

However, the thermal resistance value $\theta_{ja} [^{\circ}\text{C/W}]$ differs greatly depending on circuit board conditions. Refer to the derating curve on P.17. Also, we are taking measurements of thermal resistance value θ_{ja} of boards actually in use. Please feel free to contact our salesman. The calculated values above are only theoretical. For actual thermal design, please perform sufficient thermal evaluation for the application board used, and create the thermal design with enough margin to not exceed $T_{j\text{max}}=150^{\circ}\text{C}$. Although unnecessary with normal use, if the IC is to be used under especially strict heat conditions, please consider externally attaching a Schottky diode between the motor output terminal and GND to abate heat from the IC.

○Temperature Monitoring

In respect of BD68610EFV, there is a way to directly measure the approximate chip temperature by using the TEST terminal with a protection diode for prevention from electrostatic discharge. However, temperature monitor using this TEST terminal is only for evaluation and experimenting, and must not be used in actual usage conditions.

- (1) Measure the terminal voltage when a current of $I_{\text{diode}}=50\mu\text{A}$ flows from the TEST terminal to the GND, without supplying V_{CC} to the IC. This measurement is of the V_f voltage inside the diode.
- (2) Measure the temperature characteristics of this terminal voltage. (V_f has a linear negative temperature factor against the temperature.) With the results of these temperature characteristics, chip temperature may be calibrated from the TEST terminal voltage.
- (3) Supply V_{CC} , confirm the TEST terminal voltage while running the motor, and the chip temperature can be approximated from the results of (2).

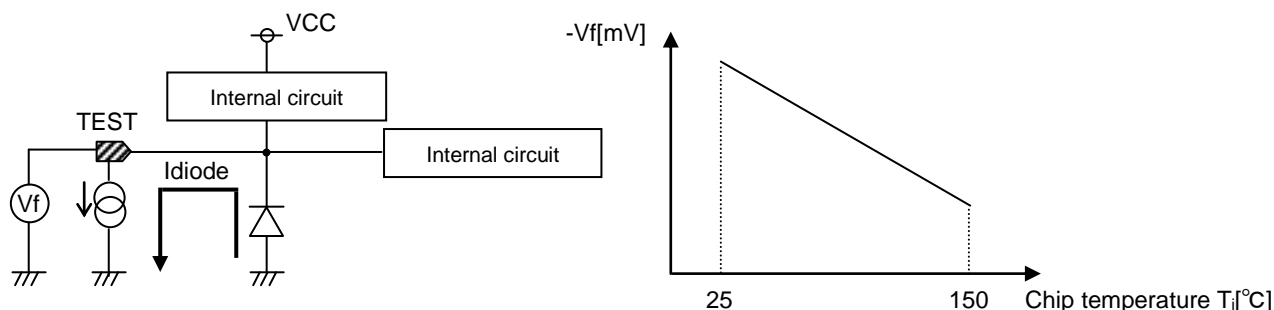


Figure 7. Model diagram for measuring chip temperature

●Example for applied circuit

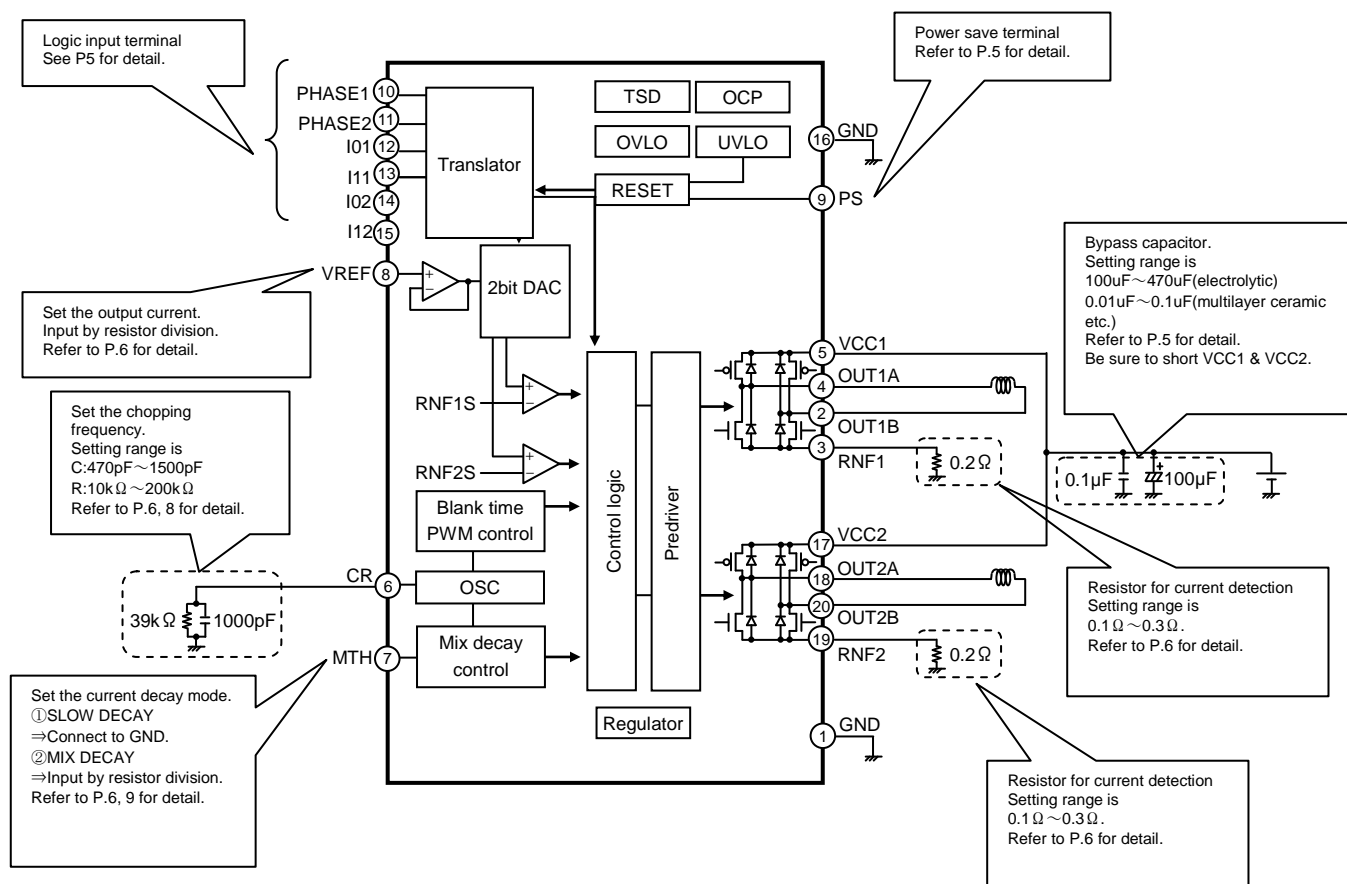


Figure 8. BD68610EFV block diagram and applied circuit diagram

● Input output equivalent circuit diagram

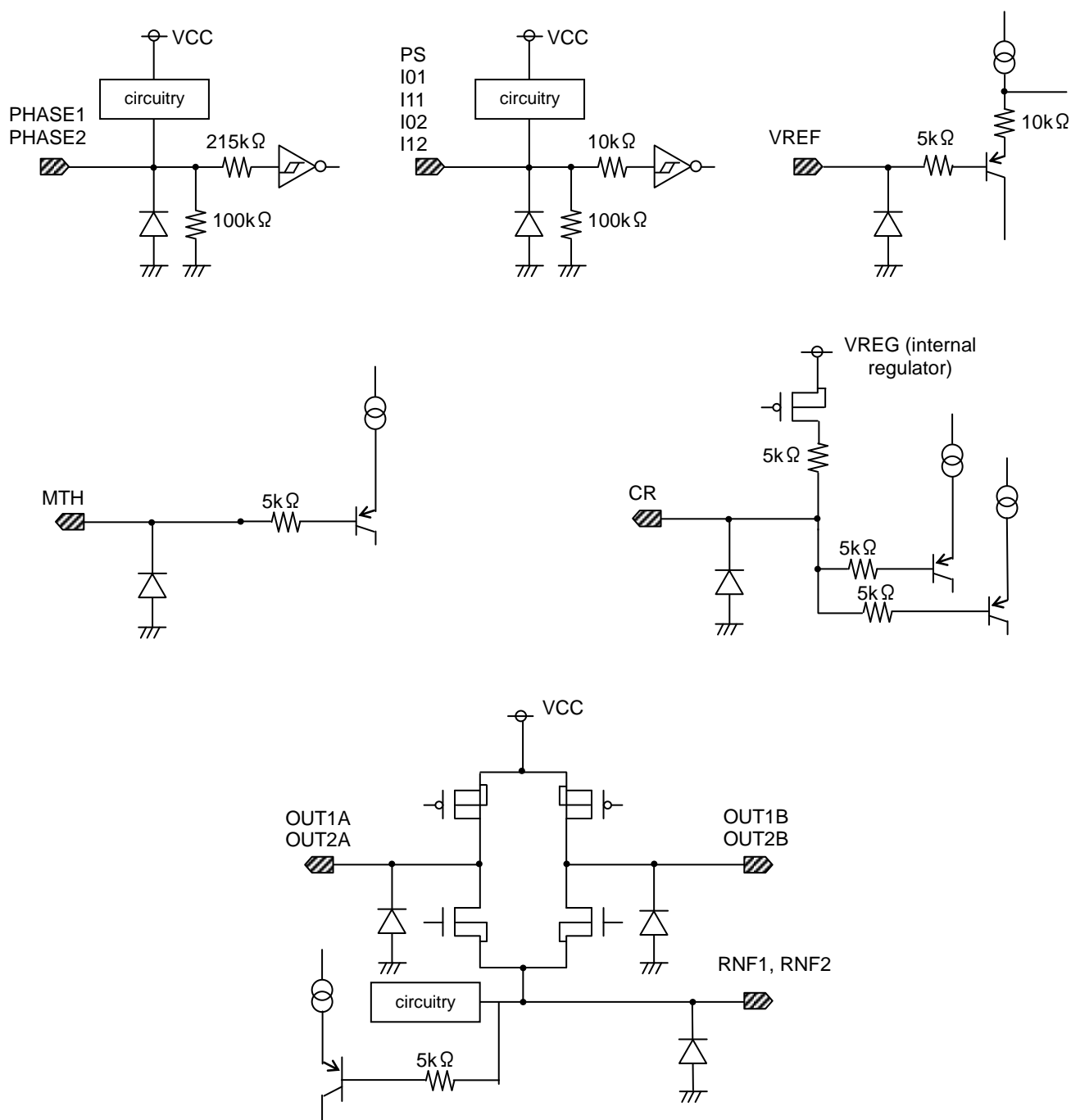


Figure 9. Input output equivalent circuit diagram

Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. The absolute maximum rating of the Pd stated in this specification is when the IC is mounted on a 70mm x 70mm x 1.6mm glass epoxy board. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

Operational Notes – continued

11. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

12. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode.

When $GND > Pin\ B$, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

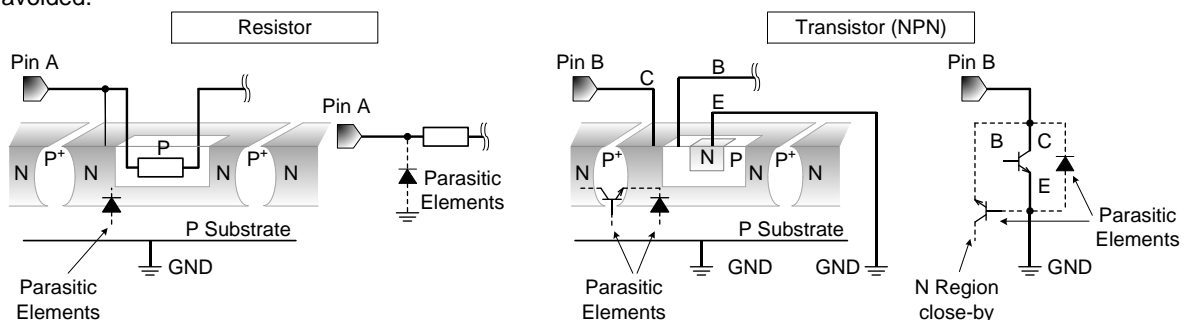


Figure 10. Example of monolithic IC structure

13. Area of Safe Operation (ASO)

Operate the IC such that the output voltage, output current, and power dissipation are all within the Area of Safe Operation (ASO).

14. Thermal Shutdown Circuit(TSD)

This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's power dissipation rating. If however the rating is exceeded for a continued period, the junction temperature (T_j) will rise which will activate the TSD circuit that will turn OFF all output pins. When the T_j falls below the TSD threshold, the circuits are automatically restored to normal operation.

Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

15. Over Current Protection Circuit (OCP)

This IC incorporates an integrated overcurrent protection circuit that is activated when the load is shorted. This protection circuit is effective in preventing damage due to sudden and unexpected incidents. However, the IC should not be used in applications characterized by continuous operation or transitioning of the protection circuit.

16. Operation Under Strong Electromagnetic Field (BD68610EFV)

The IC is not designed for using in the presence of strong electromagnetic field. Be sure to confirm that no malfunction is found when using the IC in a strong electromagnetic field.

17. Metal on the backside (Define the side where product markings are printed as front) (BD68610EFV)

The metal on the backside is shorted with the backside of IC chip therefore it should be connected to GND. Be aware that here is a possibility of malfunction or destruction if it is shorted with any potential other than GND.

● Thermal derating curve

This IC's package has exposed metal on the back, and it is possible to dissipate heat from a through hole in the back. Also, the back of board as well as the surfaces has large areas of copper foil heat dissipation patterns, greatly increasing power dissipation. The back metal is shorted with the back side of the IC chip, being a GND potential, therefore there is a possibility for malfunction if it is shorted with any potential other than GND, which should be avoided. Also, it is recommended that the back metal is soldered onto the GND to short. Please note that it has been assumed that this product will be used in the condition of this back metal performed heat dissipation treatment for increasing heat dissipation efficiency.

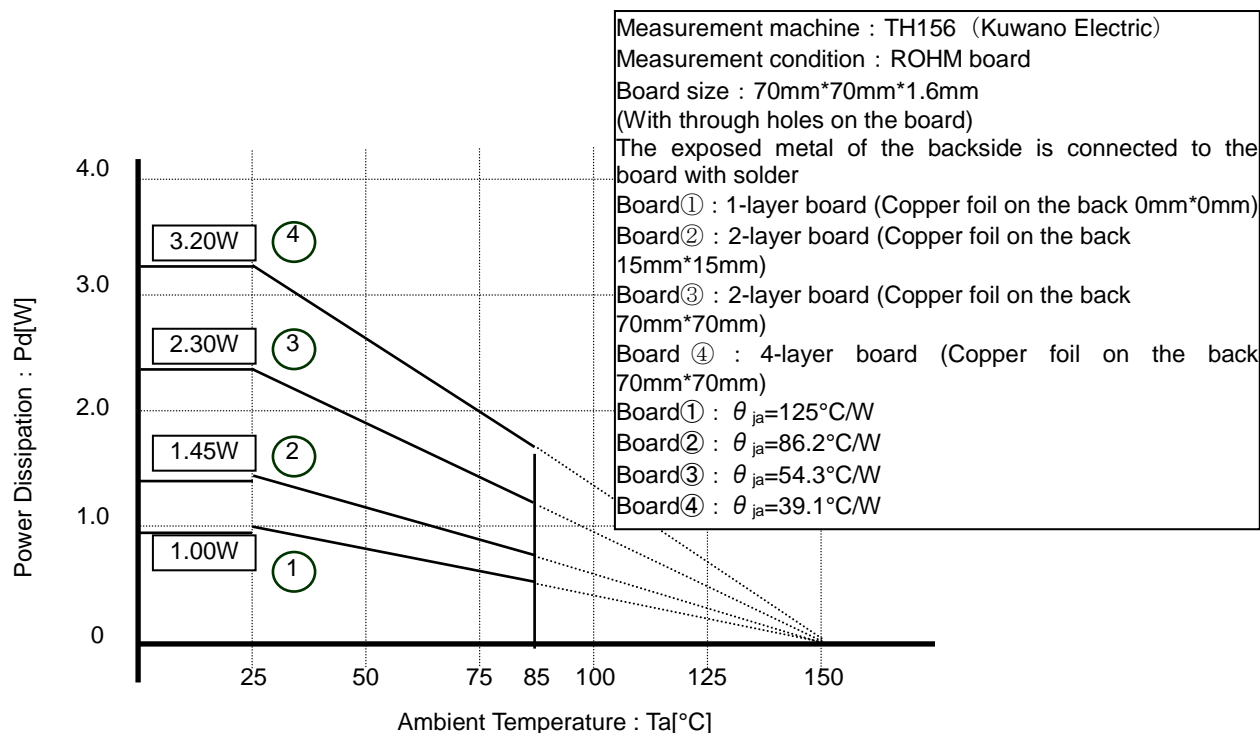
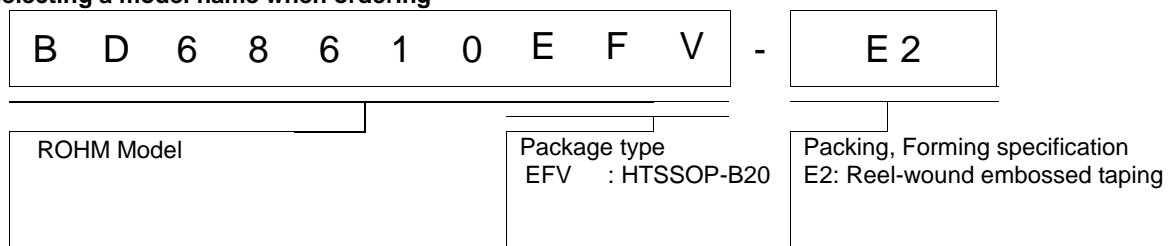
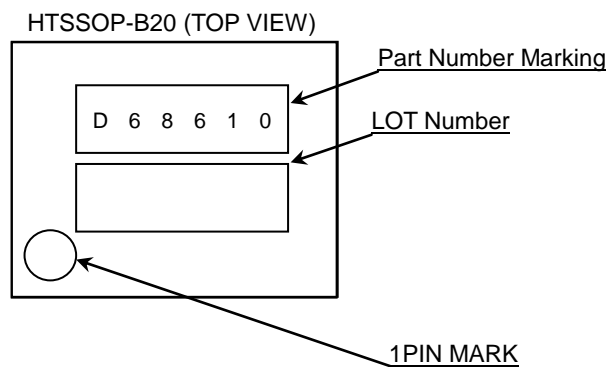


Figure 11. HTSSOP-B20 Derating Curve

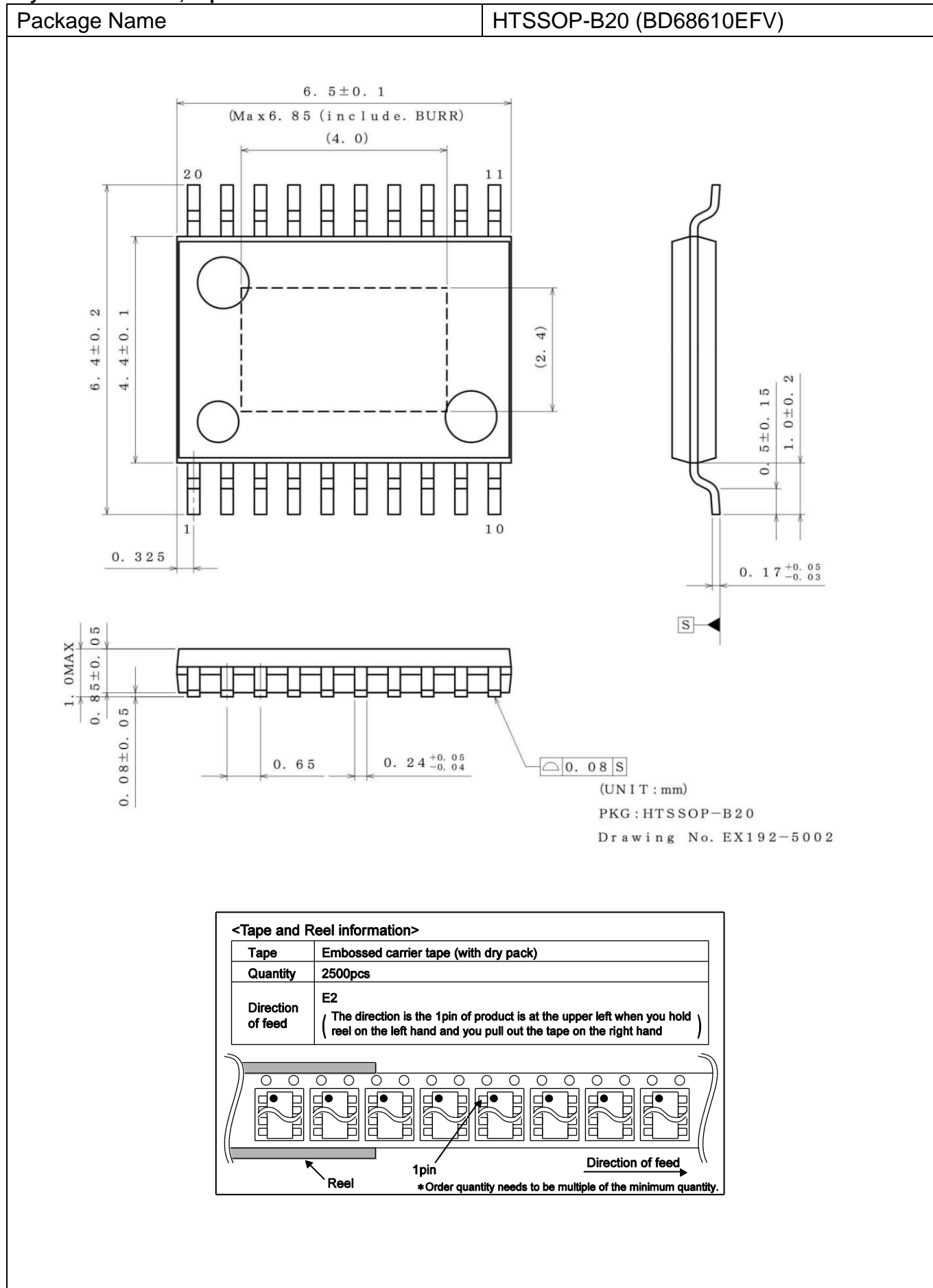
●Selecting a model name when ordering



●Marking Diagram



Physical Dimension, Tape and Reel Information



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(Note1) Medical Equipment Classification of the Specific Applications

| JAPAN | USA | EU | CHINA |
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| CLASS III | CLASS III | CLASS II b | CLASS III |
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 - Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - Sealing or coating our Products with resin or other coating materials
 - Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - Use of the Products in places subject to dew condensation
- The Products are not subject to radiation-proof design.
- Please verify and confirm characteristics of the final or mounted products in using the Products.
- In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- Confirm that operation temperature is within the specified range described in the product specification.
- ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of ionizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
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 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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